



#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

| BV <sub>DSS</sub> | RDS(ON) Max                   | I <sub>D</sub><br>T <sub>A</sub> = +25°C |
|-------------------|-------------------------------|--|
| 30V               | 60mΩ @ V <sub>GS</sub> = 10V  | 4A                                       |
| 307               | $70m\Omega$ @ $V_{GS} = 4.5V$ | 3A                                       |

### **Description**

This MOSFET has been designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

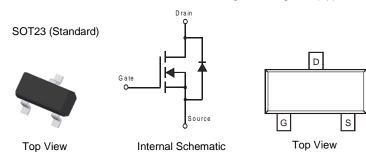
- Backlighting
- Power Management Functions
- DC-DC Converters
- Motor Control

#### **Features**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



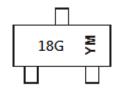
## Ordering Information (Note 4)

| Part Number | Compliance | Case             | Packaging         |
|-------------|------------|------------------|-------------------|
| DMG3418L-7  | Standard   | SOT23 (Standard) | 3000/Tape & Reel  |
| DMG3418L-13 | Standard   | SOT23 (Standard) | 10000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



18G = Product Type Marking Code YM or  $\overline{Y}M$  = Date Code Marking Y or  $\overline{Y}$  = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

| Year  | 2013 |     | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 |
|-------|------|-----|------|------|------|------|------|------|------|------|------|------|
| Code  | Α    |     | ı    | J    | K    | L    | М    | N    | 0    | Р    | R    | S    |
|       |      | 1   |      |      |      |      | 1    | 1    |      | 1    |      |      |
|       |      |     |      | _    |      |      |      |      |      |      |      | D    |
| Month | Jan  | Feb | Mar  | Apr  | May  | Jun  | Jul  | Aug  | Sep  | Oct  | Nov  | Dec  |



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

| Cha                    | racteristic                                      | Symbol          | Value      | Unit |
|------------------------|--|-----------------|------------|------|
| Drain Source Voltage   |  | VDSS            | 30         | V    |
| Gate-Source Voltage    |  | Vgss            | ±12        | V    |
| Drain Current (Note 5) | T <sub>A</sub> = +25°C<br>T <sub>A</sub> = +70°C | lD              | 4.0<br>3.1 | А    |
| Drain Current (Note 6) | Pulsed   | I <sub>DM</sub> | 15         | A    |

## **Thermal Characteristics**

| Characteristic  | Symbol   | Value       | Unit |
|---|----------|-------------|------|
| Total Power Dissipation (Note 5) $T_A = +25^{\circ}C$<br>$T_A = +70^{\circ}C$ | I Pn     | 1.4<br>0.9  | w    |
| Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)      | RθJA     | 90          | °C/W |
| Operating and Storage Temperature Range                                       | TJ, TSTG | -55 to +150 | °C   |

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                     | Symbol               | Min | Тур   | Max  | Unit | Test Condition  |  |  |
|------------------------------------|----------------------|-----|-------|------|------|---|--|--|
| OFF CHARACTERISTICS (Note 7)       | 1 - 1                | ш   |       |      |      |   |  |  |
| Drain-Source Breakdown Voltage     | BVDSS                | 30  | _     | _    | V    | Vgs = 0V, ID = 250µA  |  |  |
| Zero Gate Voltage Drain Current    | IDSS                 | _   | _     | 1    | μΑ   | V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V                 |  |  |
| Gate-Body Leakage                  | Igss                 | _   | _     | ±100 | nA   | Vgs = ±12V, Vps = 0V  |  |  |
| ON CHARACTERISTICS (Note 7)        |                      |     |       |      |      |   |  |  |
| Gate Threshold Voltage             | V <sub>G</sub> S(TH) | 0.5 | _     | 1.5  | V    | $V_{DS} = V_{GS}$ , $I_D = 250\mu A$                        |  |  |
|                                    |                      | _   | 25    | 60   |      | $V_{GS} = 10V, I_D = 4A$                                    |  |  |
| Static Drain-Source On-Resistance  | RDS(ON)              | _   | 30    | 70   | mΩ   | $V_{GS} = 4.5V, I_{D} = 3A$                                 |  |  |
|                                    |                      | _   | 50    | 150  |      | $V_{GS} = 2.5V, I_{D} = 2A$                                 |  |  |
| Source-Drain Diode Forward Voltage | VsD                  | _   | _     | 1.2  | V    | Vgs = 0V, Is = 2.0A   |  |  |
| DYNAMIC CHARACTERISTICS (Note 8)   |                      |     |       |      |      |   |  |  |
| Input Capacitance                  | Ciss                 | _   | 464.3 | _    | pF   |   |  |  |
| Output Capacitance                 | Coss                 | _   | 49.5  | _    | pF   | V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V<br>- f = 1.0MHz |  |  |
| Reverse Transfer Capacitance       | Crss                 | _   | 43.8  | _    | pF   | 1 = 1.000112  |  |  |
| Total Gate Charge                  | Qg                   | _   | 5.5   | _    |      |   |  |  |
| Gate-Source Charge                 | Q <sub>gs</sub>      | _   | 1.1   | _    | nC   | $V_{GS} = 4.5V, V_{DS} = 15V,$<br>$I_{D} = 4A$              |  |  |
| Gate-Drain Charge                  | Qgd                  | _   | 1.8   | _    |      | ID = 4A   |  |  |
| Turn-On Delay Time                 | t <sub>D(ON)</sub>   | _   | 1.9   | _    | ns   |   |  |  |
| Turn-On Rise Time                  | t <sub>R</sub>       | _   | 1.6   | _    | ns   | V <sub>DD</sub> = 15V, V <sub>GEN</sub> = 10V,              |  |  |
| Turn-Off Delay Time                | tD(OFF)              | _   | 10.3  | _    | ns   | $R_{GEN} = 3\Omega$ , $R_L = 3.75\Omega$                    |  |  |
| Turn-Off Fall Time                 | tF                   | _   | 2.0   | _    | ns   |   |  |  |

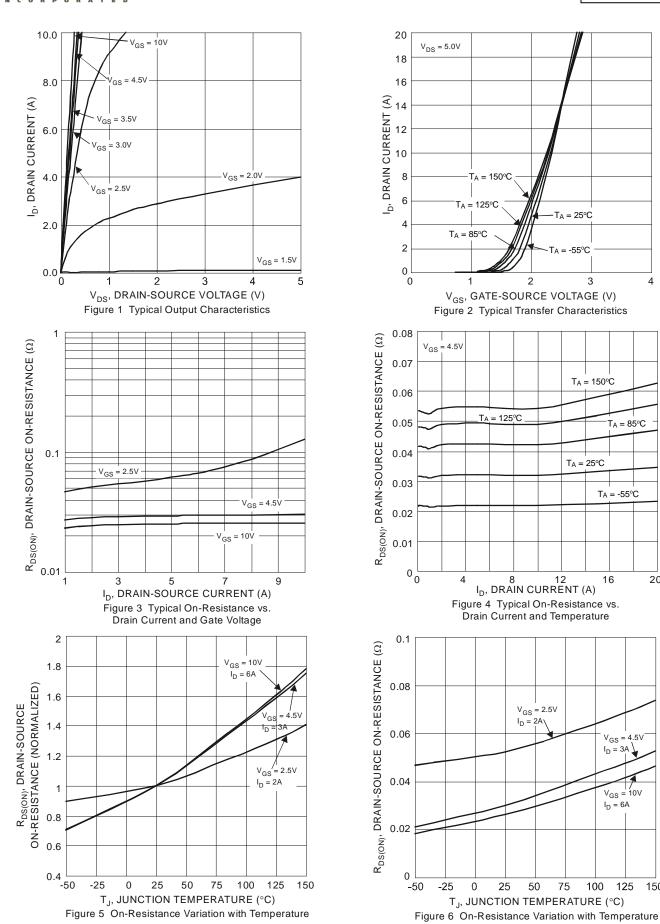
Notes:

- 5. Device mounted on FR-4 PCB with 2oz. copper and test pulse width t ≤ 10s.
  6. Repetitive rating, pulse width limited by junction temperature.
  7. Short duration pulse test used to minimize self-heating effect.
  8. Guaranteed by design. Not subject to product testing.

T<sub>A</sub> = 85°C

20





150

125



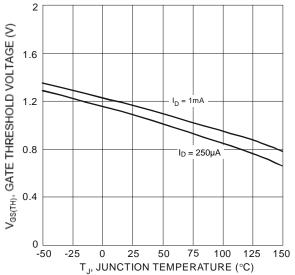
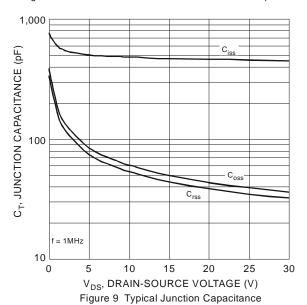
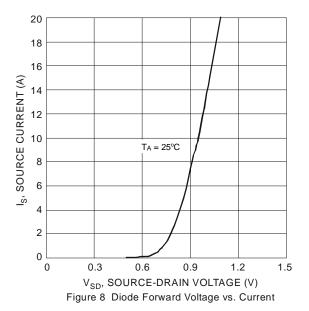


Figure 7 Gate Threshold Variation vs. Junction Temperature





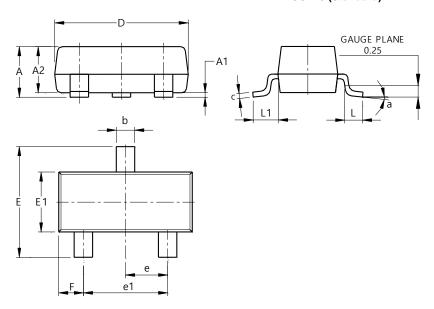
10 (X) 8 V<sub>DS</sub> = 15V I<sub>D</sub> = 4A (X) I<sub>D</sub> = 4A



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Standard)

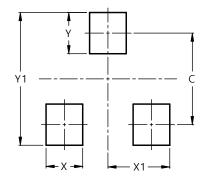


| SOT23 (Standard)     |       |       |       |  |  |  |
|----------------------|-------|-------|-------|--|--|--|
| Dim                  | Min   | Max   | Тур   |  |  |  |
| Α                    | 0.90  | 1.15  | 1.025 |  |  |  |
| A1                   | 0.00  | 0.10  | 0.05  |  |  |  |
| A2                   | 0.85  | 1.10  | 0.975 |  |  |  |
| b                    | 0.30  | 0.51  | 0.40  |  |  |  |
| С                    | 0.080 | 0.202 | 0.11  |  |  |  |
| D                    | 2.80  | 3.00  | 2.90  |  |  |  |
| Е                    | 2.25  | 2.55  | 2.40  |  |  |  |
| E1                   | 1.20  | 1.40  | 1.30  |  |  |  |
| е                    | 0.89  | 1.03  | 0.915 |  |  |  |
| e1                   | 1.78  | 2.05  | 1.83  |  |  |  |
| F                    | 0.40  | 0.60  | 0.535 |  |  |  |
| L1                   | 0.45  | 0.61  | 0.55  |  |  |  |
| L                    | 0.25  | 0.55  | 0.40  |  |  |  |
| а                    | 0°    | 8°    |       |  |  |  |
| All Dimensions in mm |       |       |       |  |  |  |

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Standard)



| Dimensions | Value (in mm) |  |  |
|------------|---------------|--|--|
| С          | 2.0           |  |  |
| Х          | 0.8           |  |  |
| X1         | 1.35          |  |  |
| Y          | 0.9           |  |  |
| Y1         | 2.9           |  |  |



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